

# Call for Papers



**Abstract Deadline:**  
November 15, 1991

## SYMPOSIA

### **A: AMORPHOUS SILICON TECHNOLOGY - 1992**

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### **B: CHEMICAL SURFACE PREPARATION, PASSIVATION AND CLEANING FOR SEMICONDUCTOR GROWTH AND PROCESSING**

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### **C: ADVANCED METALLIZATION AND PROCESSING FOR SEMICONDUCTOR DEVICES AND CIRCUITS - II**

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### **D: PHOTO-INDUCED SPACE CHARGE EFFECTS IN SEMICONDUCTORS: PHOTOCONDUCTIVITY, SPECTROSCOPY AND ELECTRO-OPTICS**

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### **E: DEFECT ENGINEERING IN SEMICONDUCTOR GROWTH, PROCESSING AND DEVICE TECHNOLOGY**

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### **F: MECHANISMS OF HETEROEPITAXIAL GROWTH**

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### **G: ELECTRONIC PACKAGING MATERIALS SCIENCE VI**

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### **H: MATERIALS RELIABILITY**

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### **Ia: MATERIALS INTERACTIONS RELEVANT TO RECYCLING OF WOOD-BASED MATERIALS**

Bruce Evans, Pfizer Specialty Minerals, (215) 861-3443, FAX (215) 861-3412; Ted Laufenberg, United States Department of Agriculture, (608) 231-9477, FAX (608) 231-9592; Roger Rowell, United States Department of Agriculture, (608) 231-9416, FAX (608) 231-9262; Stan Sobczinski, DOE Office of Industrial Programs, (202) 586-1878, FAX (202) 586-8134

**Ib: MATERIALS FOR ENERGY TECHNOLOGIES**

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**Jc: MATERIALS FOR SEPARATION TECHNOLOGY**

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**J: MATERIALS ISSUES IN ART & ARCHAEOLOGY III**

James R. Druzik, Getty Conservation Institute, (213) 822-2299, FAX (213) 821-9409; Pamela B. Vandiver, Smithsonian Institution, (301) 238-3734, FAX (301) 238-3709; George S. Wheeler, The Metropolitan Museum of Art, (212) 570-3858, FAX (212) 570-3879; I.C. Freestone, The British Museum, United Kingdom, (44) 71-636-1555, FAX (44) 71-323-8515

**K: MATERIALS MODIFICATION BY ENERGETIC ATOMS AND IONS**

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**L: MICROWAVE PROCESSING OF MATERIALS**

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**M: NOVEL FORMS OF CARBON**

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**N: BETTER CERAMICS THROUGH CHEMISTRY V**

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**O: CHEMICAL PROCESSES IN INORGANIC MATERIALS: METAL AND SEMICONDUCTOR CLUSTERS AND COLLOIDS**

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**P: AEROSOL PRECURSORS TO MATERIALS**

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**Q: INTERMETALLIC MATRIX COMPOSITES II**

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**R: SUBMICRON MULTIPHASE MATERIALS**

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**S: LAYERED SUPERCONDUCTORS: FABRICATION, PROPERTIES, AND APPLICATIONS**

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**T: DEFECT STRUCTURES IN CRYSTALLINE ELECTRONIC OXIDES**

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**U: "SMART" MATERIALS FABRICATION**

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**V: MACROMOLECULAR HOST-GUEST COMPLEXES: OPTICAL AND OPTOELECTRONIC PROPERTIES AND APPLICATIONS**

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**W: COMPUTATIONAL METHODS IN MATERIALS SCIENCE**

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**X: FRONTIERS OF MATERIALS RESEARCH**

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**Y: MATERIALS FOR MICRO-ELECTRO-MECHANICAL SYSTEMS**

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